April 1992 Revised March 2002

FAIRCHILD

SEMICONDUCTOR

# 74ABT162244 16-Bit Buffer/Line Driver with **25** $\Omega$ Series Resistors in the Outputs

# **General Description**

The ABT162244 contains sixteen non-inverting buffers with 3-STATE outputs designed to be employed as a memory and address driver, clock driver, or bus oriented transmitter/receiver. The device is nibble controlled. Individual 3-STATE control inputs can be shorted together for 8-bit or 16-bit operation.

The  $25\Omega$  series resistors in the outputs reduce ringing and eliminate the need for external resistors.

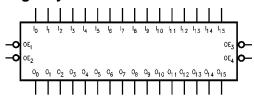
# **Features**

- Separate control logic for each nibble
- 16-bit version of the ABT2244
- Guaranteed latchup protection
- High impedance glitch free bus loading during entire power up and power down cycle
- Non-destructive hot insertion capability

# **Ordering Code:**

Order Number	Package Number	Package Description
74ABT162244CSSC	MS48A	48-Lead Small Shrink Outline Package (SSOP), JEDEC MO-118, 0.300" Wide
74ABT162244CSSX	MS48A	48-Lead Small Shrink Outline Package (SSOP), JEDEC MO-118, 0.300" Wide
74ABT162244CMTD	MTD48	48-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide
74ABT162244MTDX	MTD48	48-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide

# Logic Symbol



# **Pin Descriptions**

Pin Names	Description				
<del>OE</del> n	Output Enable Input (Active LOW)				
I <sub>0</sub> -I <sub>15</sub>	Inputs				
O <sub>0</sub> -O <sub>15</sub>	Outputs				

### **Connection Diagram** OE1 OF. 00 01 GND 02 03 Vcc 0, 05 GND 39 06 38 37 07 36 08 0, 3 GND 3 33 010 10 32 011 **h**1

V<sub>CC</sub>

012

013 20

GND

014 -

015

0E

21

23

24

3

28 - GND

27

26

25

Vcc 30

12 29

13

14

<sup>1</sup>15

- OE,

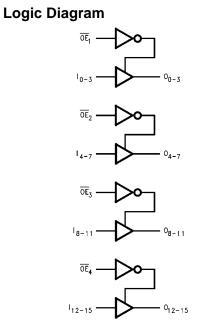
# 74ABT162244 16-Bit Buffer/Line Driver with 25 $\Omega$ Series Resistors in the Outputs

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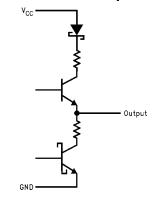
# 74ABT162244

**Truth Tables** 

In	puts	Outputs
OE <sub>1</sub>	I <sub>0</sub> –I <sub>3</sub>	O <sub>0</sub> –O <sub>3</sub>
L	L	L
L	н	н
Н	Х	Z
In	puts	Outputs
OE <sub>3</sub>	I <sub>8</sub> –I <sub>11</sub>	0 <sub>8</sub> –0 <sub>11</sub>
L	L	L
L	н	н
Н	Х	Z
In	puts	Outputs
OE <sub>2</sub>	I <sub>4</sub> –I <sub>7</sub>	0 <sub>4</sub> –0 <sub>7</sub>
OE <sub>2</sub>	l₄−l <sub>7</sub> ∟	0 <sub>4</sub> -0 <sub>7</sub>
L	L	L
L L H	L H	L H
L L H	L H X	L H Z



# Schematic of each Output



н H = HIGH Voltage Level

L = LOW Voltage Level X = Immaterial Z = High Impedance

L

# **Functional Description**

The ABT162244 contains sixteen non-inverting buffers with 3-STATE outputs. The device is nibble (4 bits) controlled with each nibble functioning identically, but independent of the other. The control pins can be shorted together to obtain full 16-bit operation.

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# Absolute Maximum Ratings(Note 1)

	-
Storage Temperature	-65°C to +150°C
Ambient Temperature under Bias	-55°C to +125°C
Junction Temperature under Bias	$-55^{\circ}C$ to $+150^{\circ}C$
V <sub>CC</sub> Pin Potential to Ground Pin	-0.5V to +7.0V
Input Voltage (Note 2)	-0.5V to +7.0V
Input Current (Note 2)	-30 mA to +5.0 mA
Voltage Applied to Any Output	
in the Disabled or	
Power-Off State	-0.5V to 5.5V
in the HIGH State	-0.5V to V <sub>CC</sub>
Current Applied to Output	
in LOW State (Max)	twice the rated I <sub>OL</sub> (mA)
DC Latchup Source Current	–500 mA
Over Voltage Latchup (I/O)	10V

# Recommended Operating Conditions

Free Air Ambient Temperature	$-40^{\circ}C$ to $+85^{\circ}C$
Supply Voltage	+4.5V to +5.5V
Minimum Input Edge Rate ( $\Delta V/\Delta t$ )	
Data Input	50 mV/ns
Enable Input	20 mV/ns

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Note 1: Absolute maximum ratings are values beyond which the device may be damaged or have its useful life impaired. Functional operation under these conditions is not implied.

Note 2: Either voltage limit or current limit is sufficient to protect inputs.

# **DC Electrical Characteristics**

Symbol	Parame	ter	Min	Тур	Max	Units	V <sub>cc</sub>	Conditions
VIH	Input HIGH Voltage		2.0			V		Recognized HIGH Signal
VIL	Input LOW Voltage				0.8	V		Recognized LOW Signal
V <sub>CD</sub>	Input Clamp Diode Volta	ge			-1.2	V	Min	I <sub>IN</sub> = -18 mA
V <sub>OH</sub>	Output HIGH Voltage		2.5			V	Min	I <sub>OH</sub> = -3 mA
			2.0			V	Min	I <sub>OH</sub> = -32 mA
V <sub>OL</sub>	Output LOW Voltage				0.8	V	Min	I <sub>OL</sub> = 12 mA
I <sub>IH</sub>	Input HIGH Current				1	μΑ	Max	V <sub>IN</sub> = 2.7V (Note 3)
					1		IVIAX	$V_{IN} = V_{CC}$
I <sub>BVI</sub>	Input HIGH Current Brea	akdown Test			7	μA	Max	V <sub>IN</sub> = 7.0V
I <sub>IL</sub>	Input LOW Current				-1	μA	Max	V <sub>IN</sub> = 0.5V (Note 3)
					-1	μΑ	IVIAX	$V_{IN} = 0.0V$
V <sub>ID</sub>	Input Leakage Test		4.75			V	0.0	I <sub>ID</sub> = 1.9 μA
								All Other Pins Grounded
I <sub>OZH</sub>	Output Leakage Current				10	μA	0-5.5V	$V_{OUT} = 2.7V; \overline{OE}_n = 2.0V$
I <sub>OZL</sub>	Output Leakage Current				-10	μA	0-5.5V	$V_{OUT} = 0.5V; \overline{OE}_n = 2.0V$
I <sub>OS</sub>	Output Short-Circuit Curr	rent	-100		-275	mA	Max	$V_{OUT} = 0.0V$
I <sub>CEX</sub>	Output High Leakage Cu	irrent			50	μΑ	Max	V <sub>OUT</sub> = V <sub>CC</sub>
I <sub>ZZ</sub>	Bus Drainage Test				100	μΑ	0.0	V <sub>OUT</sub> = 5.5V; All Others GND
I <sub>CCH</sub>	Power Supply Current				2.0	mA	Max	All Outputs HIGH
I <sub>CCL</sub>	Power Supply Current				60	mA	Max	All Outputs LOW
I <sub>CCZ</sub>	Power Supply Current				2.0	mA	Max	$\overline{OE}_n = V_{CC}$
								All Others at V <sub>CC</sub> or GND
ICCT	Additional I <sub>CC</sub> /Input	Outputs Enabled			3.0	mA		$V_{I} = V_{CC} - 2.1V$
		Outputs 3-STATE			3.0	mA	Max	Enable Input V <sub>I</sub> = V <sub>CC</sub> - 2.1V
		Outputs 3-STATE			50	μA		Data Input $V_I = V_{CC} - 2.1V$
								All Others at V <sub>CC</sub> or GND
ICCD	Dynamic I <sub>CC</sub> No Load (Note 3)				0.1	mA/	Mox	Outputs OPEN
						MHz	Max	$\overline{OE}_n = GND$
								One Bit Toggling, 50% Duty Cycl

Note 3: Guaranteed, but not tested.

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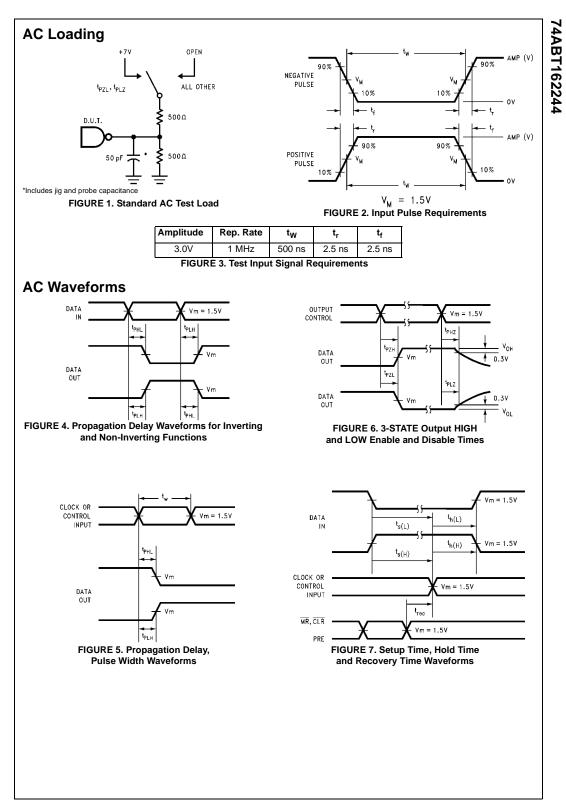
# **AC Electrical Characteristics**

Symbol	Parameter		$T_A = +25^{\circ}C$ $V_{CC} = +5V$ $C_L = 50 \text{ pF}$		$T_A = -40^{\circ}C \text{ to } +85^{\circ}C$ $V_{CC} = 4.5V - 5.5V$ $C_L = 50 \text{ pF}$		Units
		Min	Тур	Max	Min	Max	
t <sub>PLH</sub>	Propagation	1.0	2.4	3.9	1.0	3.9	ns
t <sub>PHL</sub>	Delay Data to Outputs	1.0	3.2	4.7	1.0	4.7	115
t <sub>PZH</sub>	Output	1.5	3.5	6.3	1.5	6.3	20
t <sub>PZL</sub>	Enable Time	1.5	4.2	6.9	1.5	6.9	ns
t <sub>PHZ</sub>	Output	1.0	4.2	6.7	1.0	6.7	
t <sub>PLZ</sub>	Disable Time	1.0	3.8	6.7	1.0	6.7	ns

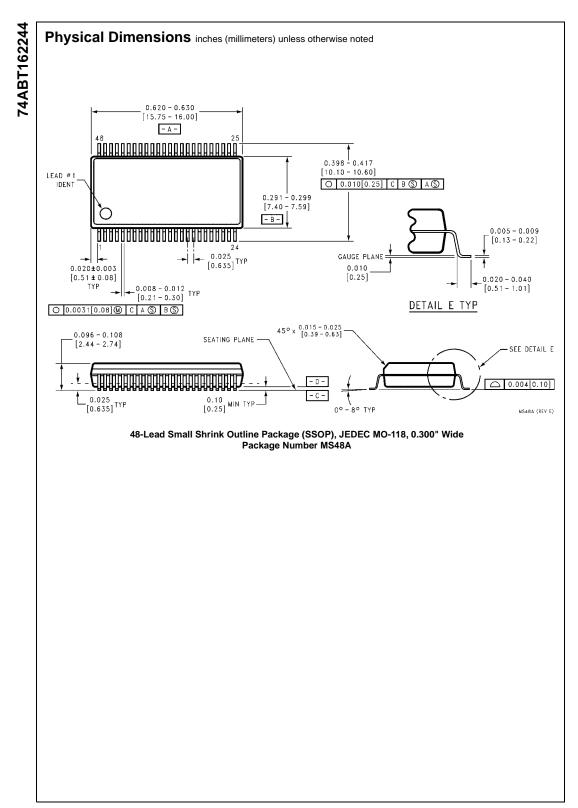
# Capacitance

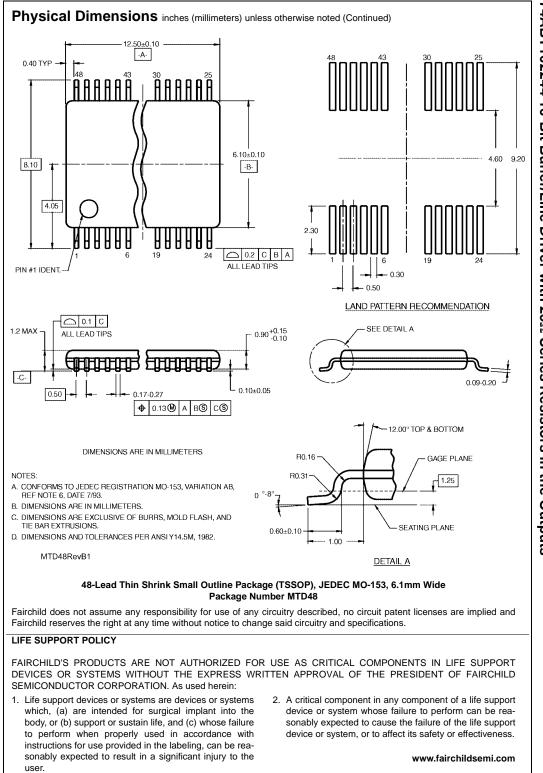
Symbol	Parameter	Тур	Units	Conditions T <sub>A</sub> = 25°C
C <sub>IN</sub>	Input Capacitance	5.0	pF	$V_{CC} = 0.0V$
C <sub>OUT</sub> (Note 4)	Output Capacitance	9.0	pF	$V_{CC} = 5.0V$

Note 4:  $C_{OUT}$  is measured at frequency f = 1 MHz per MIL-STD-883, Method 3012.



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